

isc Silicon NPN Power Transistor

2SC1456

DESCRIPTION

- With TO-66 Package
- · Low collector saturation voltage
- Minimum Lot-to-Lot variations for robust device performance and reliable operation.

APPLICATIONS

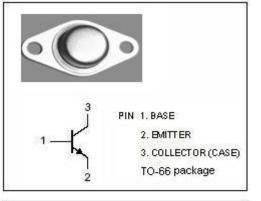
 Designed for switching and wide-band amplifier applications

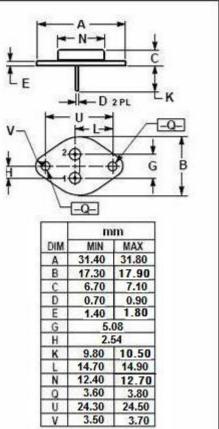


SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	300	V
V _{CEO}	Collector-Emitter Voltage 30		V
V _{EBO}	Emitter-Base Voltage 5		V
lc	Collector Current-Continuous 0.15		А
Pc	Collector Power Dissipation @ Tc=25°C	10	W
TJ	Junction Temperature 150		°C
T _{stg}	Storage Temperature Range -55		°C
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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	12.5	°C/W





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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 50mA; I _B = 5mA		2.0	V
Ісво	Collector Cutoff Current	V _{CB} = 200V;I _B = 0		10	uA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 4V; I _C =0		10	uA
h _{FE}	DC Current Gain	I _C = 50mA ; V _{CE} = 10V	30	150	

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